

Switching Losses Test

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1/22/2020



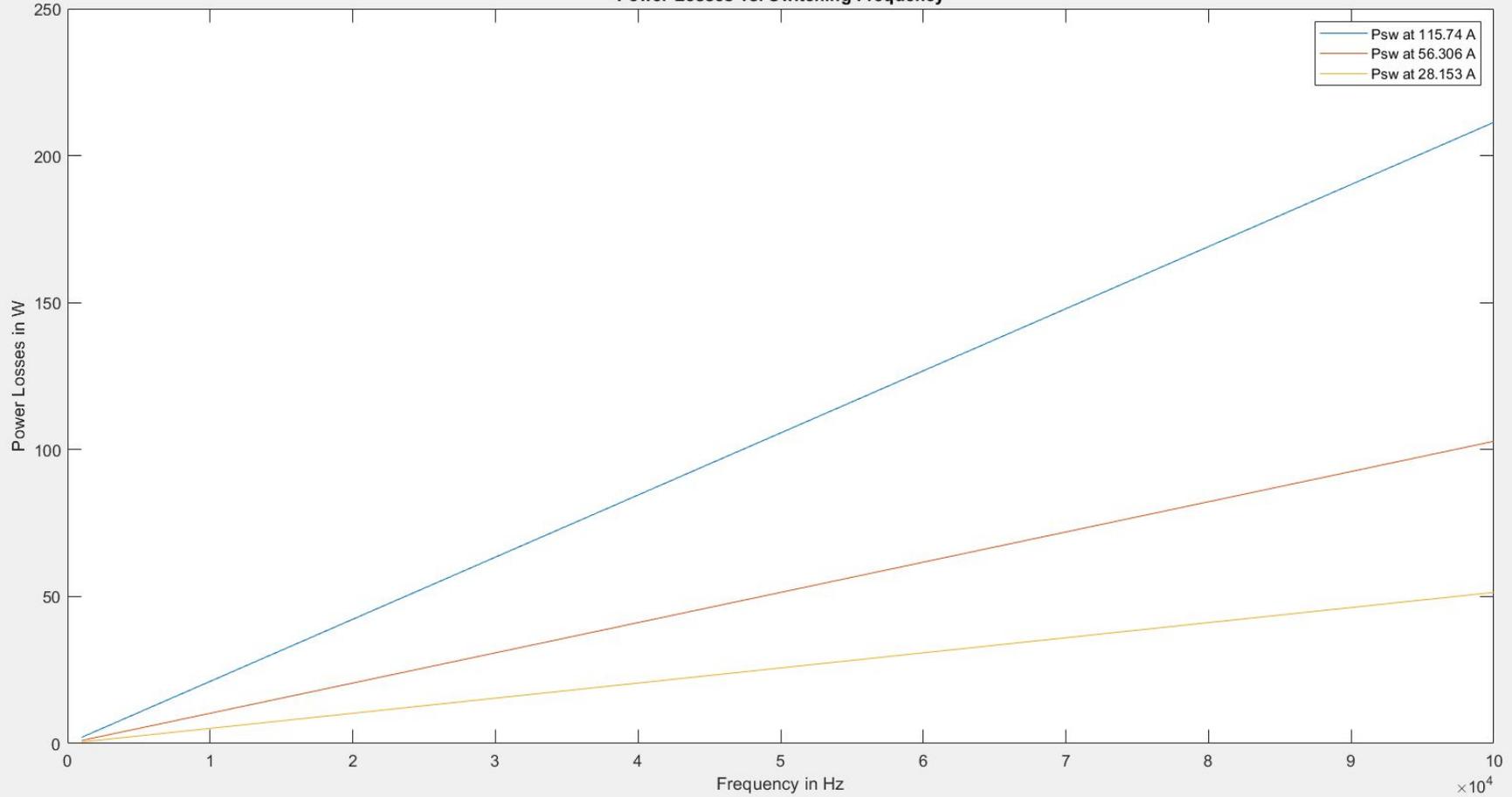
Parameters

- **Used Equation $P_{sw} = V_{in} \cdot I_{out} \cdot F_{sw} \cdot Q_{gate} / I_g$**
- **Used DC Bus voltage of $144 \cdot 3.7$ V**
- **Rdson of 7.38 nOhms (at 125C)**
- **Calculated I_g Using gate capacitance, 15 V/-5 V Vgs, and fall time for 125C**
- **Calculated Q for 600 V**
 - Assumed $Q = V \cdot C$
 - Used $Q1/V1 = Q2/V2$ ratio
 - Inaccurate for highly variable gate capacitance
- **Switching frequencies variable from 1 kHz to 100 kHz**
- **Tested at three different currents**
 - $I_{peak} = 115.7$ A (50 kW)
 - $I_{nominal} = 56.3$ A (30 kW)
 - $I_{light} = 28.15$ A (15 kW)
- **It should be noted that this is for one switching module, not for the entire inverter.**



Results

Power Losses vs. Switching Frequency



Results

- **We can see a linear relationship between power losses and switching frequency.**
 - This is supported by many of the online resources I could find
 - The highest likely switching frequency will be around 40 kHz, in which case we get a switching loss of about 85 Watts per switch, or a total of 510 Watts per Inverter
- **This is not 100% accurate as some characteristics change with temperature and I was unable to find those equations**
 - A more accurate calculation would include the variation in these parameters.
- **The values shown in the graph match those of other examples of switching losses within SiC MOSFETS**
 - Plan on a follow up calculation for last year's switches and the switches within the Lenze Inverters (if able to find)

- **Resources:**

- [Texas Instruments](#)

- [Toshiba](#)

